



TS824-1.2

HIGH THERMAL STABILITY MICROPOWER SHUNT VOLTAGE REFERENCE

- LOW Tc: 50 ppm/°C MAXIMUM
- 1.225V OUTPUT VOLTAGE
- LOW OPERATING CURRENT: 45µA max @ 25°C
- HIGH PRECISION AT 25°C: ±1%
- STABLE WHEN USED WITH CAPACITIVE LOADS
- INDUSTRIAL TEMPERATURE RANGE: -40 to +85°C

DESCRIPTION

The TS824 is a low power shunt voltage reference featuring a very low temperature coefficient of 50ppm/°C as a maximum value. Providing 1.225V output voltage, the TS824 operates over the industrial temperature range (-40 to +85°C). Ideal for battery-powered equipments where power conservation is critical, the TS824 is housed in a tiny SOT23-3 package allowing space saving.

The TS824 is typically stable with any capacitive loads within the entire temperature range. The product is thus easy to use and the design simplified.

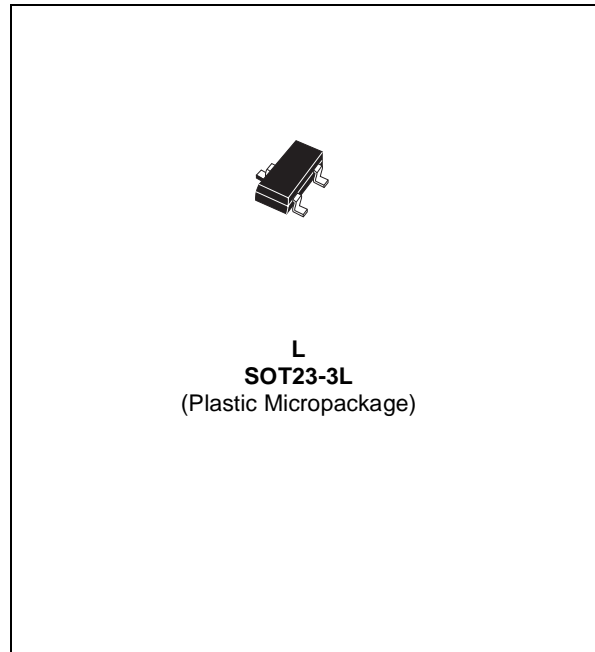
APPLICATION

- Instrumentation,
- Data acquisition systems,
- Portable, Battery powered equipments
- Power management

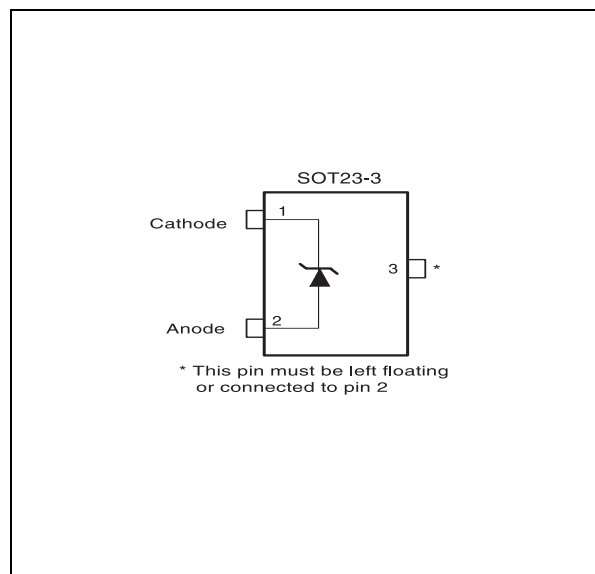
ORDER CODE

Voltage	Precision	SOT23-3	SOT23 Marking
1.225V	1%	TS824ILT-1.2	L251
Single temperature range: -40 to +85°C			

LT = Tiny Package (SOT23-3) - only available in Tape & Reel (LT)



PIN CONNECTIONS (top view)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
I_K	Reverse Breakdown Current	20	mA
I_F	Forward Current	10	mA
P_D	Power Dissipation (note 1) SOT23-3	360	mW
T_{Std}	Storage Temperature	-65 to +150	°C
T_J	Junction Temperature	+150	°C
T_{Lead}	Lead Temperature (soldering, 10 seconds)	+260	°C
ESD	Human Body Model (HBM) (note 2)	2	kV
	Machine Model (MM) (note 2)	200	V

Note 1: The maximum power dissipation must be derated at high temperature. It can be calculated using T_{JMAX} (maximum junction temperature), R_{THJA} (Thermal resistance junction to ambient) and T_A (Ambient temperature). The maximum power dissipation formula at any temperature is $P_{DMAX} = (T_{JMAX} - T_A) / R_{THJA}$. R_{THJA} is 340°C/W for the SOT23-3 package.

Note 2: The Human Body Model (HBM) is defined as a 100pF capacitor discharge through a 1.5kΩ resistor into each pin. The Machine Mode (MM) is defined as a 200pF capacitor discharge directly into each pins.

OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
I_{min}	Minimum Operating Current	40	μA
I_{max}	Maximum Operating Current	12	mA
T_{oper}	Operating Free Air Temperature Range	-40 to +85	°C

ELECTRICAL CHARACTERISTICS (note 3)

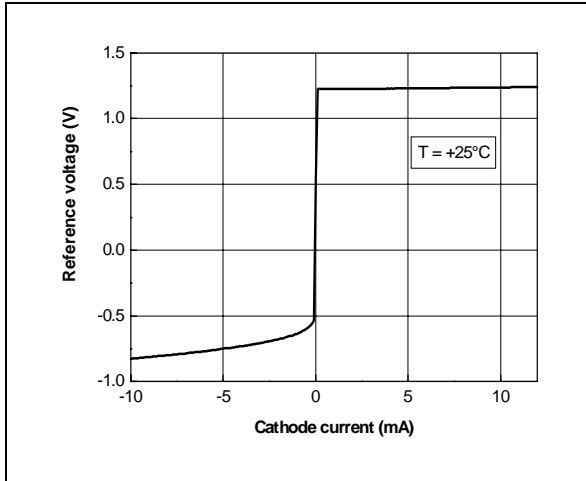
$T_{amb} = 25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
V_K	Reverse Breakdown Voltage	$I_K = 100\mu\text{A}$	1.213	1.225	1.237	V
	Reverse Breakdown Voltage Tolerance	$I_K = 100\mu\text{A}$ $-40^\circ\text{C} < T_{amb} < +85^\circ\text{C}$	-12 -16		+12 +16	mV
I_{KMIN}	Minimum Operating Current	$T_{amb} = 25^\circ\text{C}$		40	45	μA
		$-40^\circ\text{C} < T_{amb} < +85^\circ\text{C}$			50	
$\Delta V_K / \Delta T$	Average Temperature Coefficient (note 4)	$I_K = 100\mu\text{A}$			50	ppm/°C
$\Delta V_K / \Delta I_K$	Reverse Breakdown Voltage Change with Operating Current Range	$I_{KMIN} < I_K < 1\text{mA}$ $-40^\circ\text{C} < T_{amb} < +85^\circ\text{C}$		0.3	1 1.5	mV
		$1\text{mA} < I_K < 12\text{mA}$ $-40^\circ\text{C} < T_{amb} < +85^\circ\text{C}$		2.5	8 10	
R_{KA}	Static Impedance	$\Delta I_K = I_{KMIN}$ to 1mA $-40^\circ\text{C} < T_{amb} < +85^\circ\text{C}$		0.3	1 1.5	Ω
		$\Delta I_K = 1\text{mA}$ to 12mA $-40^\circ\text{C} < T_{amb} < +85^\circ\text{C}$		0.25	0.7 0.9	
K_{VH}	Long Term Stability	$I_K = 100\mu\text{A}$, $t = 1000\text{hrs}$		120		ppm
E_N	Wide Band Noise	$I_K = 100\mu\text{A}$ $100\text{Hz} < f < 10\text{kHz}$		200		nV/√Hz

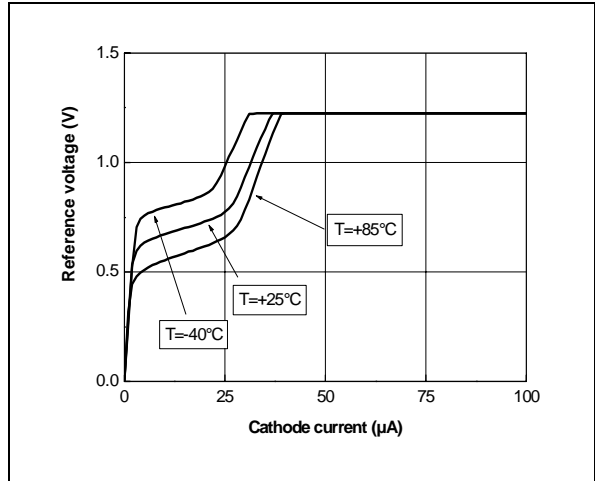
Note 3: Limits are 100% production tested at 25°C. Limits over temperature are guaranteed through correlation and by design.

Note 4: The total tolerance within the industrial range, where the maximum ΔT versus 25°C is 65°C, is explained hereafter:
 $\pm 1\% + (\pm 50 \text{ ppm}/^\circ\text{C} \times 65^\circ\text{C}) = \pm 1.325\%$

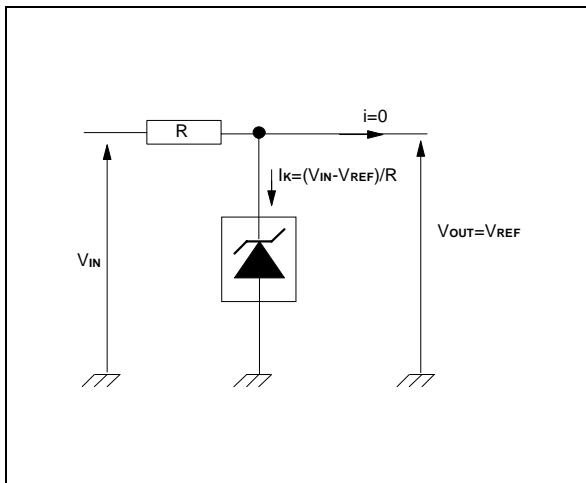
Reference voltage versus cathode current



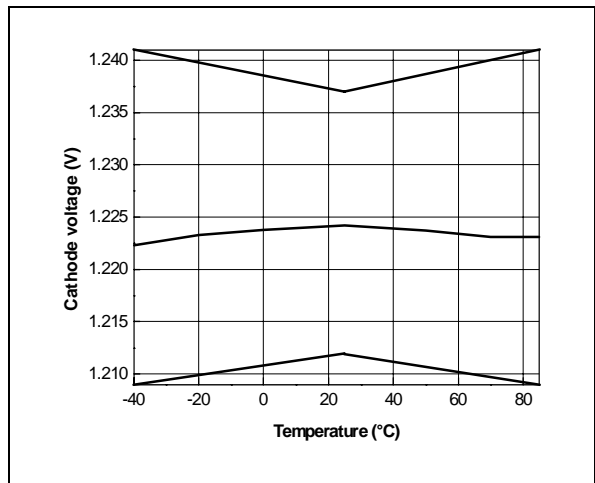
Reference voltage versus cathode current



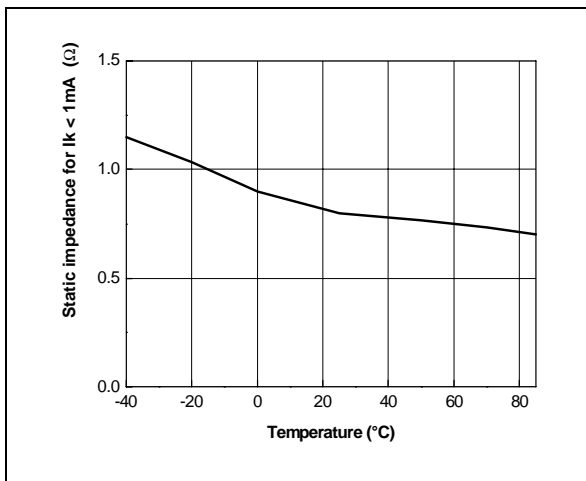
Test circuit



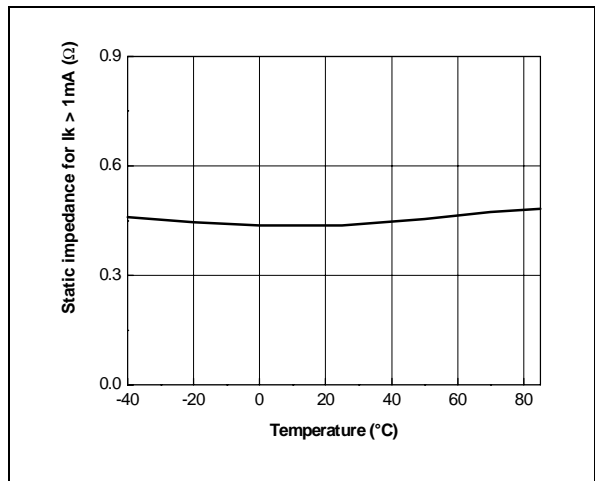
Reference voltage versus Temperature



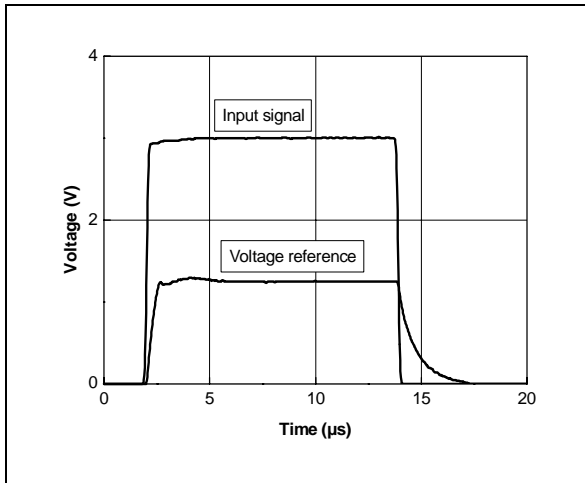
Static impedance for $I_k < 1\text{mA}$



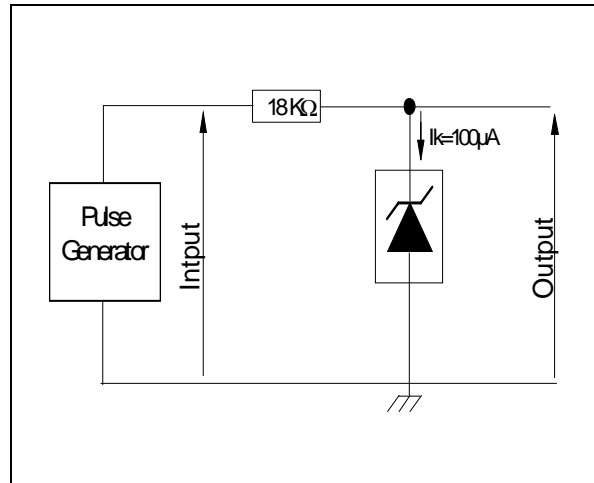
Static impedance for $I_k > 1\text{mA}$



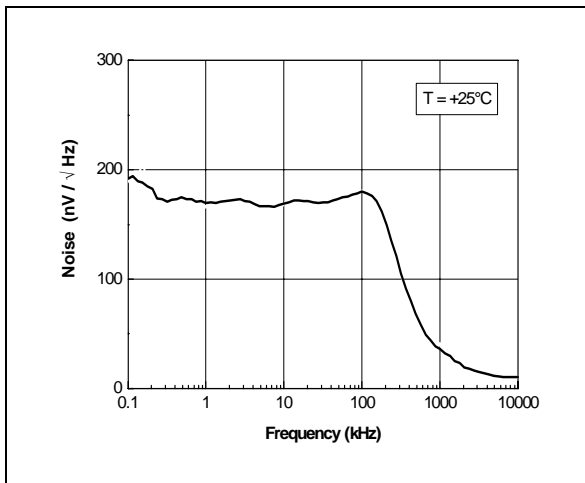
Start-Up characteristics with low I_k (100 μ A)



Start-Up schematic with low I_k (100 μ A)

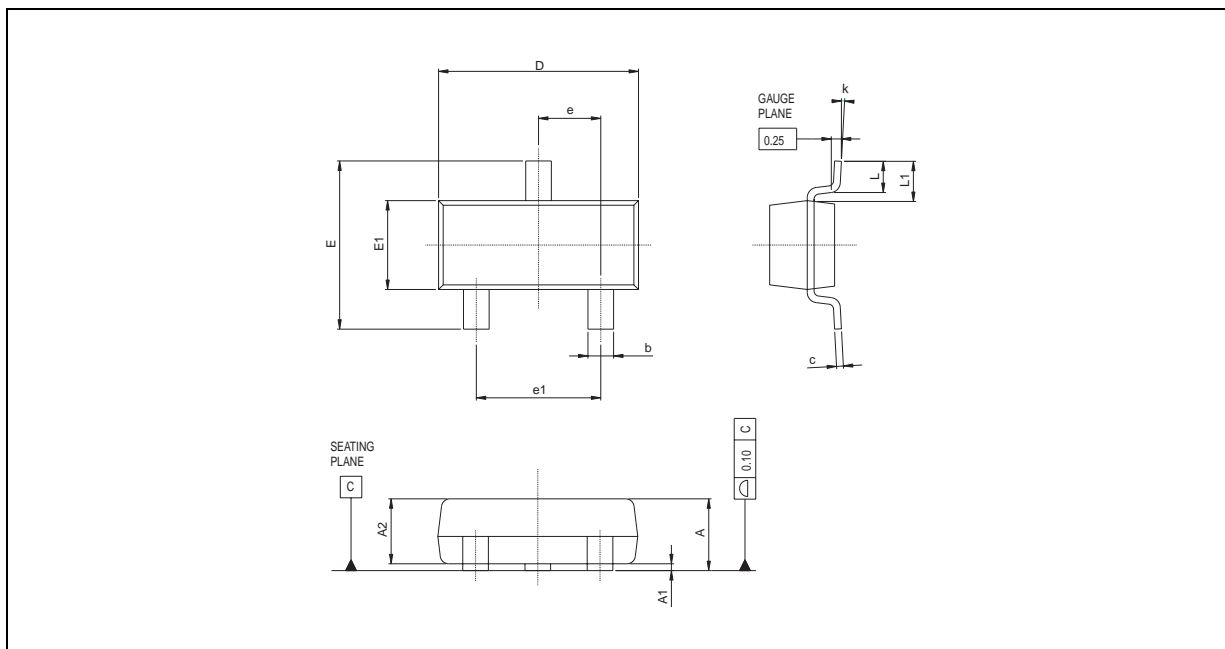


Noise versus frequency



PACKAGE MECHANICAL DATA

3 PINS - TINY PACKAGE (SOT23-3)



Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.890		1.120	0.035		0.044
A1	0.010		0.100	0.0004		0.004
A2	0.880	0.950	1.020		0.037	0.040
b	0.300		0.500	0.012		0.020
c	0.080		0.200	0.003		0.008
D	2.800	2.900	3.040	0.110	0.114	0.120
E	2.100		2.640	0.083		0.104
E1	1.200	1.300	1.400	0.047	0.051	0.055
e		0.950			0.037	
e1		1.900			0.075	
L	0.400	0.500	0.600	0.016	0.020	0.024
L1		0.540			0.021	
k	0°		8°			

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

© The ST logo is a registered trademark of STMicroelectronics

© 2002 STMicroelectronics - Printed in Italy - All Rights Reserved
STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia
Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States

© <http://www.st.com> - United Kingdom



Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9